

MOS FIELD EFFECT TRANSISTOR **2SK3110**

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3110 is N channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter, actuator driver.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3110	Isolated TO-220

FEATURES

- •Gate voltage rating ±30 V
- •Low on-state resistance

RDS(on) = 180 $m\Omega$ MAX. (Vgs = 10 V, Ip = 7.0 A)

•Low input capacitance

Ciss = 1000 pF TYP. (VDS = 10 V, VGS = 0 V)

- •Built-in gate protection diode
- Avalanche capability rated
- •Isolated TO-220 package

ABSOLUTE MAXIMUM RATING $(T_A = 25^{\circ}C)$

Drain to Source Voltage (Vgs = 0 V)	VDSS	200	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±30	V
Drain Current(DC) (Tc = 25°C)	ID(DC)	±14	Α
Drain Current(pulse) Note1	D(pulse)	±42	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	2.0	W
Total Power Dissipation (Tc = 25°C)	PT2	35	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	14	Α
Single Avalanche Energy Note2	Eas	98	mJ

Note1. PW \leq 10 μ s, Duty Cycle \leq 1 %

2. Starting Tch = 25°C, VDD = 100 V, RG = 25 Ω , VGS = 20 V \rightarrow 0 V

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

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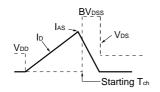
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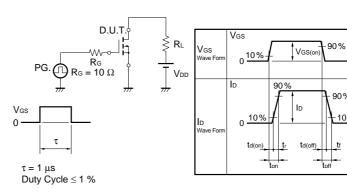
ELECTRICAL CHARACTERISTICS (TA = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Drain Leakage Current	IDSS	Vps = 200 V, Vgs = 0 V			100	μΑ
Gate Leakage Current	Igss	Vgs = ±30 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	VGS(off)	VDS = 10 V, ID = 1 mA	2.5		4.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 7.0 A	3.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, ID = 7.0 A		120	180	mΩ
Input Capacitance	Ciss	Vps = 10 V		1000		pF
Output Capacitance	Coss	VGS = 0 V		300		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		150		pF
Turn-on Delay Time	td(on)	VDD = 100 V, ID = 7.0 A		25		ns
Rise Time	tr	VGS(on) = 10 V		70		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		80		ns
Fall Time	t f			40		ns
Total Gate Charge	QG	VDD = 160 V		40		nC
Gate to Source Charge	Qgs	Vgs = 10 V		7		nC
Gate to Drain Charge	QGD	ID = 14 A		25		nC
Diode Forward Voltage	VF(S-D)	IF = 14 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 14 A, VGS = 0 V		300		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		1.5		μC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

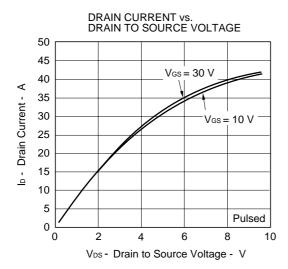


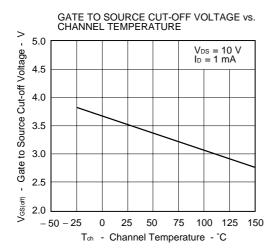
TEST CIRCUIT 2 SWITCHING TIME

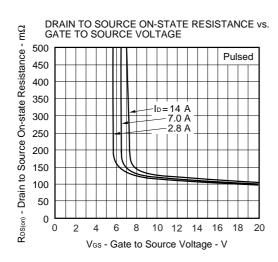


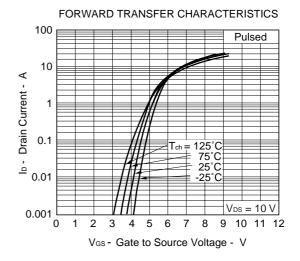
TEST CIRCUIT 3 GATE CHARGE

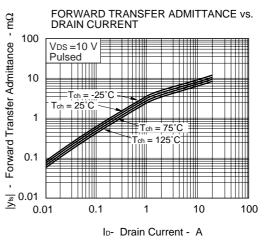
★ TYPICAL CHARACTERISTICS (TA = 25°C)

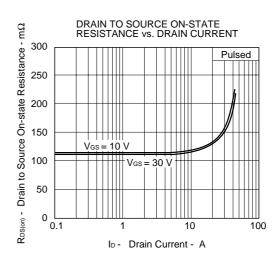


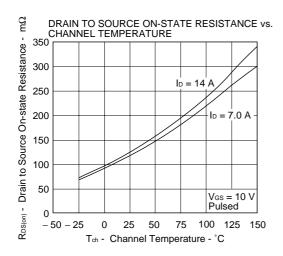


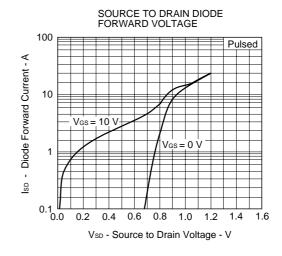


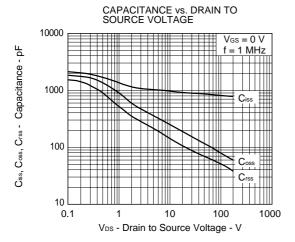


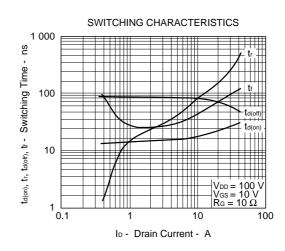


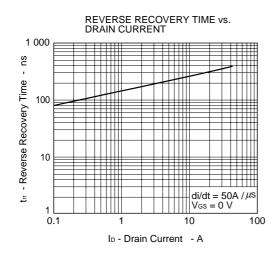


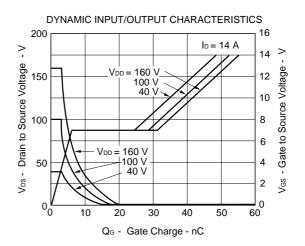


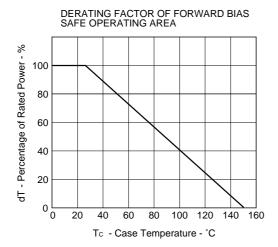


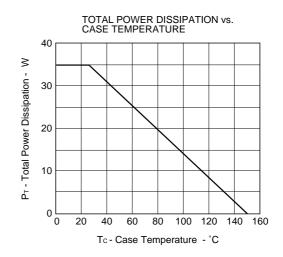


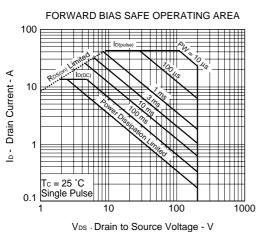




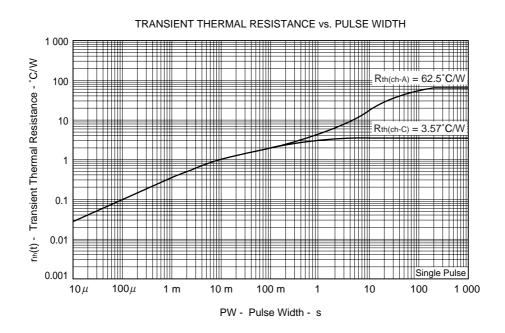


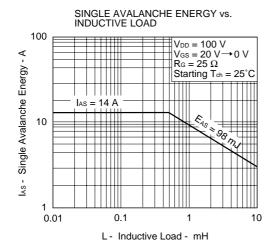




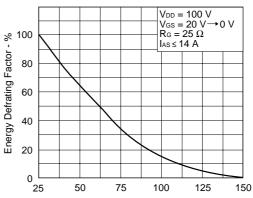


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SINGLE AVALANCHE ENERGY DERATING FACTOR

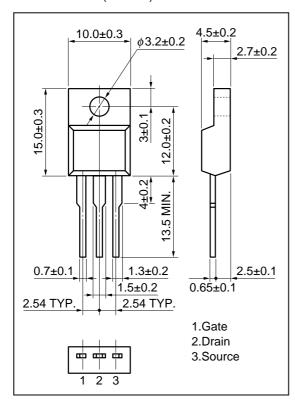


Starting Tch - Starting Channel Temperature - °C

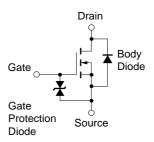


PACKAGE DRAWING(Unit: mm)

Isolated TO-220 (MP-45F)



EQUIVALENT CIRCUIT



The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

NEC 2SK3110

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